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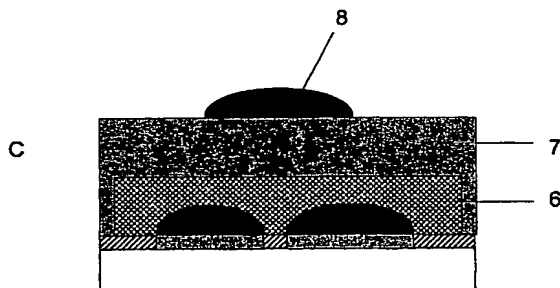
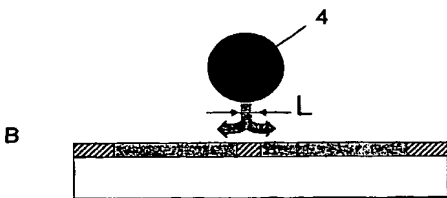
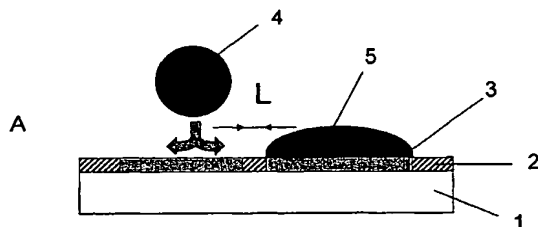
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(54) Title: SEMICONDUCTING ISLAND AS ACTIVE LAYER IN FET



(57) Abstract: A method for forming an electronic device including at least one electrically conductive and one semiconductive material deposited from solution, the method comprising: forming on the substrate a confinement structure consisting of a least a first zone and a second zone, depositing the electrically conductive material on the substrate, wherein the electrically conductive material is absent from both the first and second zone, and subsequently depositing the electrically semiconductive material from solution, wherein the semiconductive material is absent from the first zone, but not from the second zone.



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Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

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## C. DOCUMENTS CONSIDERED TO BE RELEVANT

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Y	the whole document	
X	WO 01/46987 A (PLASTIC LOGIC LTD ; SIRRINGHAUS HENNING (GB); KAWASE TAKEO (GB); FRIEN) 28 June 2001 (2001-06-28)	1,2,5-7, 10, 12-19, 22, 33-35, 37,38, 48,50,51 45-47
Y	page 6, line 17 - page 7, line 3 page 42, line 17 - line 21; figure 21a ----- -/--	

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## C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

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